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# ADD-A-PAK Generation VII Power Modules Standard Diodes, 80 A



ADD-A-PAK

PRODUCT SUMMARY	
I <sub>F(AV)</sub>	80 A
Туре	Modules - Diode, High Voltage
Package	ADD-A-PAK
Circuit	Two diodes doubler circuit, Two diodes common cathode, Two diodes common anode, Single diode

#### **MECHANICAL DESCRIPTION**

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

#### **FEATURES**

- High voltage
- Industrial standard package



- · Low thermal resistance
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **BENEFITS**

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- · High surge capability
- · Easy mounting on heatsink

#### **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	110 °C	80				
I <sub>F(RMS)</sub>		126	۸			
I <sub>FSM</sub>	50 Hz	1500	Α			
	60 Hz	1570				
I <sup>2</sup> t	50 Hz	11.25	kA <sup>2</sup> s			
1-1	60 Hz	10.26	KA <sup>-</sup> S			
I <sup>2</sup> √t		112.5	kA²√s			
V <sub>RRM</sub>	Range	400 to 1600	V			
T <sub>J</sub>		-40 to 150	°C			
T <sub>Stg</sub>		-40 (0 150	C			



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#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = 150 °C mA				
	04	400	500					
	06	600	700					
	08	800	900					
VS-VSK.71	10	1000	1100	10				
	12	1200	1300					
	14	1400	1500					
	16	1600	1700					

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current at case temperature	I <sub>F(AV)</sub>	180° condu	ction, half sine	wave	80 110	A °C
Maximum RMS forward current	I <sub>F(RMS)</sub>	DC at 90 °C	case temperat	ure	126	C
	. (	t = 10 ms	No voltage		1500	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		1570	А
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		1260	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1320	
	l <sup>2</sup> t	t = 10 ms	No voltage	intitial T <sub>J</sub> = T <sub>J</sub> maximum	11.25	kA <sup>2</sup> s
Maximum I2t for fusing		t = 8.3  ms	reapplied		10.26	
waximum i-t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		7.95	
		t = 8.3  ms	reapplied		7.23	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	112.5	kA <sup>2√</sup> s
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	$I_{F(AV)}$ , $T_J = T_J$ maximum	0.73	V
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)})$	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			ľ
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum			3.22	mΩ
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			2.89	11152
Maximum forward voltage drop	$V_{FM}$	$I_{FM} = \pi \times I_{F(A)}$	<sub>AV)</sub> , T <sub>J</sub> = 25 °C,	t <sub>p</sub> = 400 μs square wave	1.6	V

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum peak reverse leakage current	I <sub>RRM</sub>	T <sub>J</sub> = 150 °C	10	mA		
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	3000 (1 min) 3600 (1 s)	V		



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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	/MBOL TEST CONDITIONS		UNITS	
Junction and storage temp	erature range	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C	
Maximum internal thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.28	2044	
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.1	°C/W	
Mounting toyour 10.0/	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of	4	Nm	
Mounting torque ± 10 % busbar			3 hours to allow for the spread of the compound.	3	INIII	
Approximate weight				75	g	
Approximate weight				2.7	oz.	
Case style			JEDEC®	ADD-A-PAK Ger	n. VII (TO-240AA)	

△R CONDUCTION PER JUNCTION											
DEVICES		SINE HALF	WAVE CO	NDUCTIO	7	RECTANGULAR WAVE CONDUCTION			N	LIMITE	
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.71	0.075	0.088	0.113	0.155	0.228	0.06	0.094	0.12	0.158	0.23	°C/W

#### Note

Table shows the increment of thermal resistance R<sub>th,JC</sub> when devices operate at different conduction angles than DC



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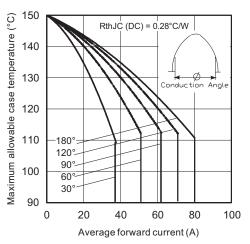


Fig. 1 - Current Ratings Characteristics

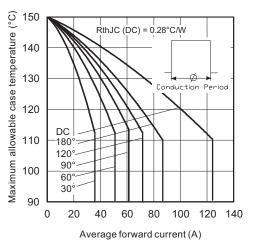


Fig. 2 - Current Ratings Characteristics

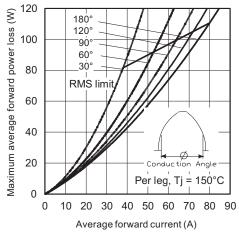


Fig. 3 - Forward Power Loss Characteristics

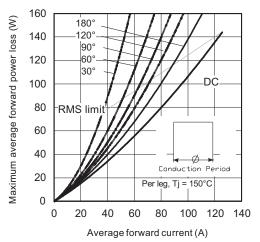
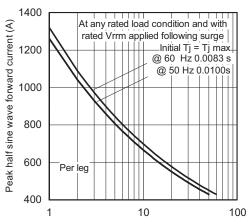


Fig. 4 - Foward Power Loss Characteristics



Number of equal amplitude half cycle current pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

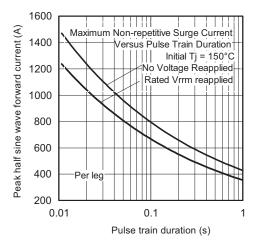


Fig. 6 - Maximum Non-Repetitive Surge Current

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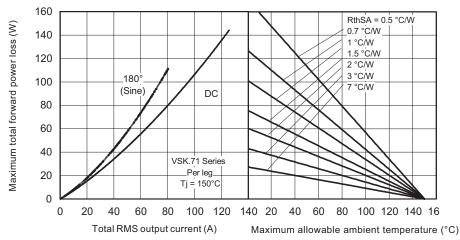


Fig. 7 - Forward Power Loss Characteristics

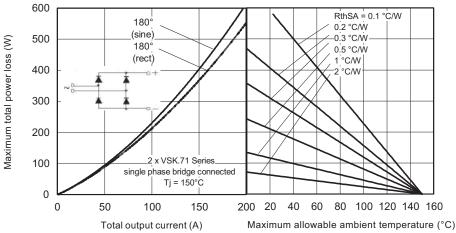


Fig. 8 - Forward Power Loss Characteristics

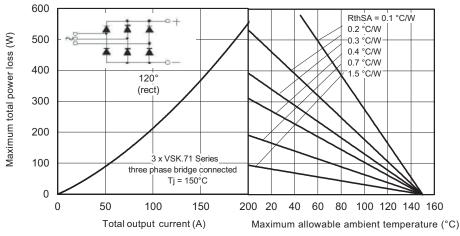


Fig. 9 - Forward Power Loss Characteristics

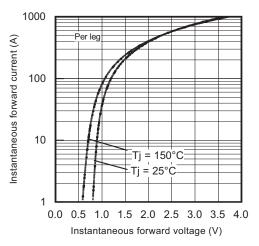


Fig. 10 - Forward Voltage Characteristics

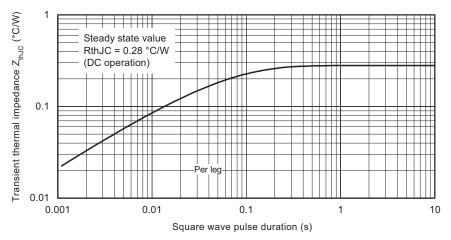
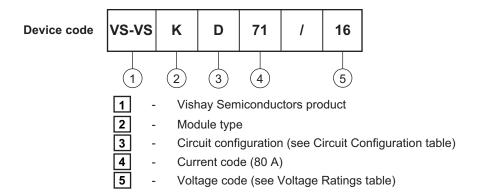


Fig. 11 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**



#### Note

• To order the optional hardware go to <a href="www.vishay.com/doc?95172">www.vishay.com/doc?95172</a>



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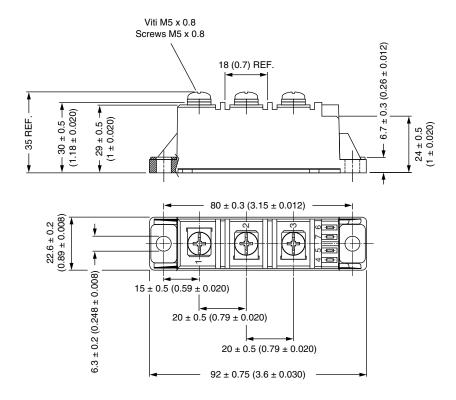
CIRCUIT CONFIGURATION						
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
		<b>VSKD</b> (1) ~ (2) (3)				
Two diodes doubler circuit	D					
Two diodes common cathode	С	VSKC  (1) 0				
Two diodes common danieds						
		VSKJ  (1) 0 + (2) (3)				
Two diodes common anode	J					
		VSKE				
Single diode	E	(2) ÷ (3)				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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### **ADD-A-PAK Generation VII - Diode**

#### **DIMENSIONS** in millimeters (inches)





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